LM339, LM339E, LM239, LM2901, LM2901E, LM2901V, NCV2901, MC3302

Single Supply Quad Comparators

These comparators are designed for use in level detection, low−level sensing and memory applications in consumer, automotive, and industrial electronic applications.

Features

- Single or Split Supply Operation
- Low Input Bias Current: 25 nA (Typ)
- Low Input Offset Current: ±5.0 nA (Typ)
- Low Input Offset Voltage
- Input Common Mode Voltage Range to GND
- Low Output Saturation Voltage: 130 mV (Typ) @ 4.0 mA
- TTL and CMOS Compatible
- ESD Clamps on the Inputs Increase Reliability without Affecting Device Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

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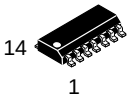
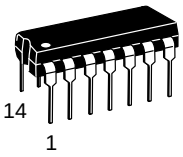
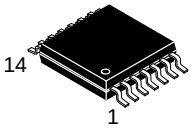


SOIC−14
D SUFFIX
CASE 751A

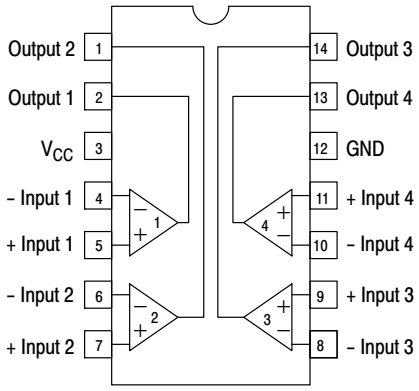


PDIP−14
N, P SUFFIX
CASE 646



TSSOP−14
DTB SUFFIX
CASE 948G

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

DEVICE MARKING INFORMATION

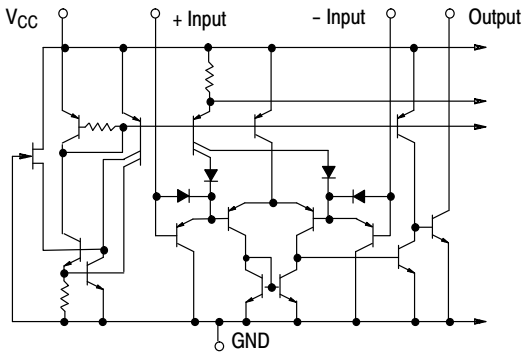
See general marking information in the device marking section on page 8 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage LM239/LM339, E/LM2901, E, V MC3302	V_{CC}	 +36 or ±18 +30 or ±15	Vdc
Input Differential Voltage Range LM239/LM339, E/LM2901, E, V MC3302	V_{IDR}	 36 30	Vdc
Input Common Mode Voltage Range	V_{ICMR}	−0.3 to V_{CC}	Vdc
Output Short Circuit to Ground (Note 1)	I_{SC}	Continuous	
Power Dissipation @ T_A = 25°C Plastic Package Derate above 25°C	P_D $1/R_{\theta JA}$	 1.0 8.0	 W mW/°C
Junction Temperature	T_J	150	°C
Operating Ambient Temperature Range LM239 MC3302 LM2901, LM2901E LM2901V, NCV2901 LM339, LM339E	T_A	 −25 to +85 −40 to +85 −40 to +105 −40 to +125 0 to +70	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
ESD Protection at any Pin (Note 2) Human Body Model Machine Model	V_{ESD}	 1500 200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}. Output short circuits to V_{CC} can cause excessive heating and eventual destruction.
2. V_{ESD} rating for NCV/SC devices is: Human Body Model − 2000 V; Machine Model − 200 V.



NOTE: Diagram shown is for 1 comparator.

Figure 1. Circuit Schematic

ELECTRICAL CHARACTERISTICS (V_{CC} = +5.0 Vdc, T_A = +25°C, unless otherwise noted)

Characteristic	Symbol	LM239/339/339E			LM2901/2901E/2901V /NCV2901			MC3302			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (Note 4)	V_{IO}	−	±2.0	±5.0	−	±2.0	±7.0	−	±3.0	±20	mVdc
Input Bias Current (Notes 4, 5) (Output in Analog Range)	I_{IB}	−	25	250	−	25	250	−	25	500	nA
Input Offset Current (Note 4)	I_{IO}	−	±5.0	±50	−	±5.0	±50	−	±3.0	±100	nA
Input Common Mode Voltage Range	V_{ICMR}	0	−	V_{CC} −1.5	0	−	V_{CC} −1.5	0	−	V_{CC} −1.5	V
Supply Current	I_{CC}										mA
R_L = ∞ (For All Comparators)		−	0.8	2.0	−	0.8	2.0	−	0.8	2.0	
R_L = ∞, V_{CC} = 30 Vdc		−	1.0	2.5	−	1.0	2.5	−	1.0	2.5	
Voltage Gain R_L ≥ 15 kΩ, V_{CC} = 15 Vdc	A_{VOL}	50	200	−	25	100	−	25	100	−	V/mV
Large Signal Response Time V_I = TTL Logic Swing, V_{ref} = 1.4 Vdc, V_{RL} = 5.0 Vdc, R_L = 5.1 kΩ	−	−	300	−	−	300	−	−	300	−	ns
Response Time (Note 6) V_{RL} = 5.0 Vdc, R_L = 5.1 kΩ	−	−	1.3	−	−	1.3	−	−	1.3	−	μs
Output Sink Current V_I (−) ≥ +1.0 Vdc, V_I(+) = 0, V_O ≤ 1.5 Vdc	I_{Sink}	6.0	16	−	6.0	16	−	6.0	16	−	mA
Saturation Voltage V_I(−) ≥ +1.0 Vdc, V_I(+) = 0, I_{sink} ≤ 4.0 mA	V_{sat}	−	130	400	−	130	400	−	130	500	mV
Output Leakage Current V_I(+) ≥ +1.0 Vdc, V_I(−) = 0, V_O = +5.0 Vdc	I_{OL}	−	0.1	−	−	0.1	−	−	0.1	−	nA

3. (LM239) T_{low} = −25°C, T_{high} = +85°
   (LM339, LM339E) T_{low} = 0°C, T_{high} = +70°C
   (MC3302) T_{low} = −40°C, T_{high} = +85°C
   (LM2901), LM2901E T_{low} = −40°C, T_{high} = +105°
   (LM2901V & NCV2901) T_{low} = −40°C, T_{high} = +125°C
   NCV2901 is qualified for automotive use.
4. At the output switch point, $V_O \simeq$ 1.4 Vdc, $R_S \leq$ 100 Ω 5.0 Vdc ≤ V_{CC} ≤ 30 Vdc, with the inputs over the full common mode range (0 Vdc to V_{CC} −1.5 Vdc).
5. The bias current flows out of the inputs due to the PNP input stage. This current is virtually constant, independent of the output state.
6. The response time specified is for a 100 mV input step with 5.0 mV overdrive. For larger signals, 300 ns is typical.

PERFORMANCE CHARACTERISTICS (V_{CC} = +5.0 Vdc, $T_A = T_{low}$ to T_{high} [Note 7])

Characteristic	Symbol	LM239/339/339E			LM2901/2901E/2901V /NCV2901			MC3302			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (Note 8)	V_{IO}	–	–	±9.0	–	–	±15	–	–	±40	mVdc
Input Bias Current (Notes 8, 9) (Output in Analog Range)	I_{IB}	–	–	400	–	–	500	–	–	1000	nA
Input Offset Current (Note 8)	I_{IO}	–	–	±150	–	–	±200	–	–	±300	nA
Input Common Mode Voltage Range	V_{ICMR}	0	–	V_{CC} −2.0	0	–	V_{CC} −2.0	0	–	V_{CC} −2.0	V
Saturation Voltage $V_I(-) \geq +1.0$ Vdc, $V_I(+) = 0$, $I_{sink} \leq 4.0$ mA	V_{sat}	–	–	700	–	–	700	–	–	700	mV
Output Leakage Current $V_I(+) \geq +1.0$ Vdc, $V_I(-) = 0$, $V_O = 30$ Vdc	I_{OL}	–	–	1.0	–	–	1.0	–	–	1.0	μA
Differential Input Voltage All $V_I \geq 0$ Vdc	V_{ID}	–	–	V_{CC}	–	–	V_{CC}	–	–	V_{CC}	Vdc

7. (LM239) $T_{low} = -25°C$, $T_{high} = +85°$
   (LM339, LM339E) $T_{low} = 0°C$, $T_{high} = +70°C$
   (MC3302) $T_{low} = -40°C$, $T_{high} = +85°C$
   (LM2901, LM2901E) $T_{low} = -40°C$, $T_{high} = +105°$
   (LM2901V & NCV2901) $T_{low} = -40°C$, $T_{high} = +125°C$
   NCV2901 is qualified for automotive use.
8. At the output switch point, $V_O \simeq 1.4$ Vdc, $R_S \leq 100\ \Omega$ 5.0 Vdc ≤ V_{CC} ≤ 30 Vdc, with the inputs over the full common mode range (0 Vdc to V_{CC} −1.5 Vdc).
9. The bias current flows out of the inputs due to the PNP input stage. This current is virtually constant, independent of the output state.
10. The response time specified is for a 100 mV input step with 5.0 mV overdrive. For larger signals, 300 ns is typical.

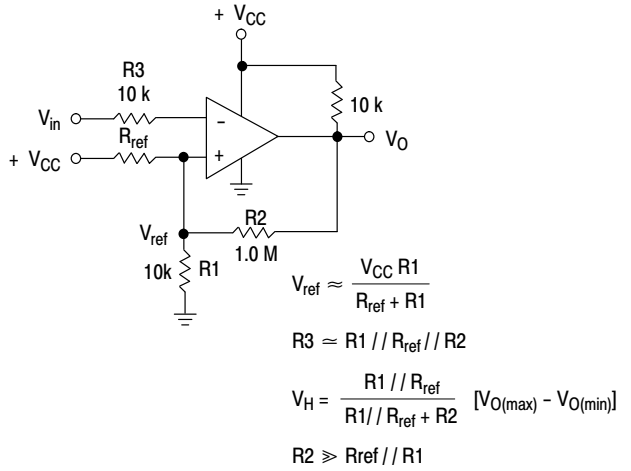


Figure 2. Inverting Comparator with Hysteresis

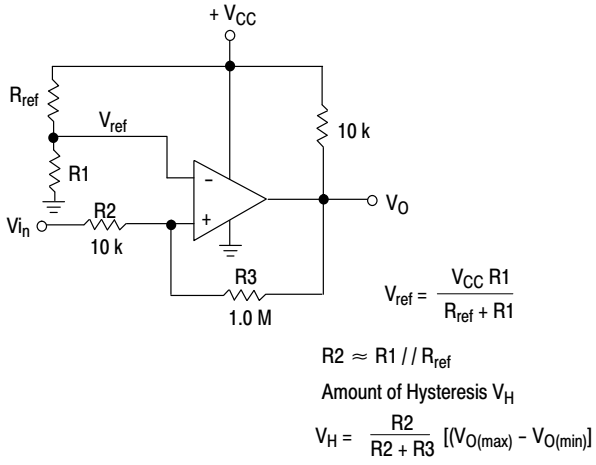


Figure 3. Noninverting Comparator with Hysteresis

Typical Characteristics

(V_{CC} = 15 Vdc, T_A = +25°C (each comparator) unless otherwise noted.)

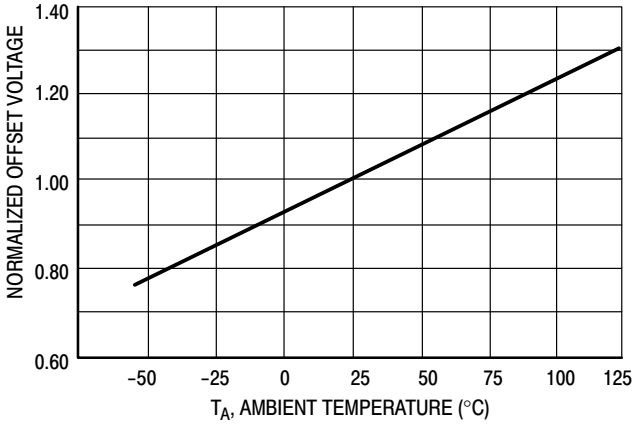


Figure 4. Normalized Input Offset Voltage

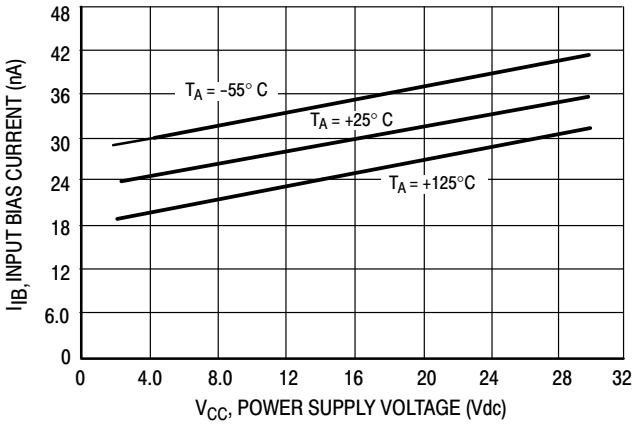


Figure 5. Input Bias Current

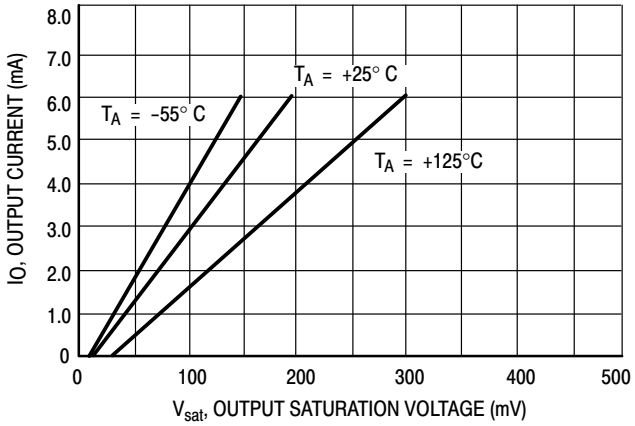
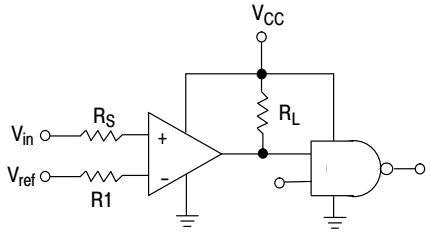


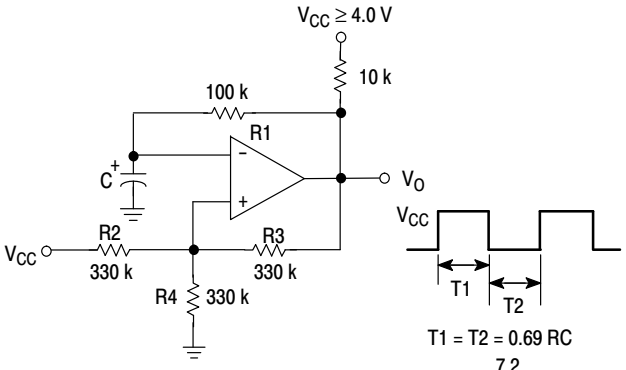
Figure 6. Output Sink Current versus Output Saturation Voltage



R_S = Source Resistance
$R1 \simeq R_S$

Logic	Device	V_{CC} (V)	R_L kΩ
CMOS	1/4 MC14001	+15	100
TTL	1/4 MC7400	+5.0	10

Figure 7. Driving Logic



T1 = T2 = 0.69 RC

$f \approx \frac{7.2}{C(\mu F)}$

R2 = R3 = R4

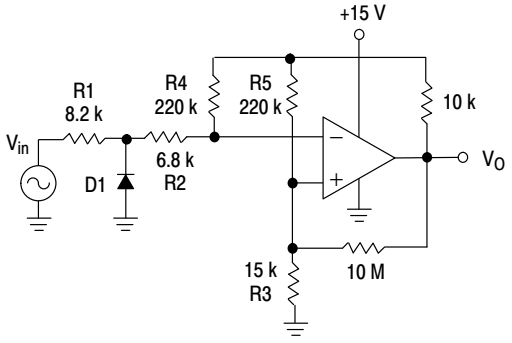
R1 ≈ R2 // R3 // R4

Figure 8. Squarewave Oscillator

APPLICATIONS INFORMATION

These quad comparators feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitively coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions (V_{OL} to V_{OH}). To alleviate this situation input resistors < 10 kΩ should be used. The addition of positive feedback (< 10 mV) is also recommended. It is good design practice to ground all unused input pins.

Differential input voltages may be larger than supply voltages without damaging the comparator's inputs. Voltages more negative than −300 mV should not be used.



D1 prevents input from going negative by more than 0.6 V.

$$R1 + R2 = R3$$

$$R3 \leq \frac{R5}{10} \text{ for small error in zero crossing}$$

Figure 9. Zero Crossing Detector (Single Supply)

$V_{in(min)} \approx 0.4$ V peak for 1% phase distortion ($\Delta\theta$).

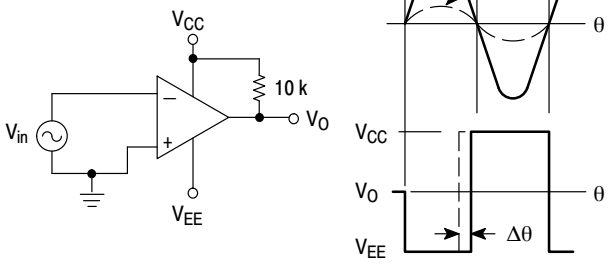


Figure 10. Zero Crossing Detector (Split Supplies)

ORDERING INFORMATION

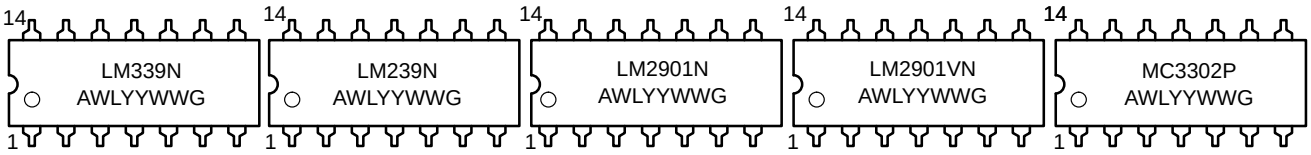
Device	Package	Shipping†
LM239DG	SOIC−14 (Pb−Free)	55 Units/Tube
LM239DR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM239DTBR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
LM239NG	PDIP−14 (Pb−Free)	25 Units/Rail
LM339DG	SOIC−14 (Pb−Free)	55 Units/Tube
LM339DR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM339EDR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM339DTBR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
LM339NG	PDIP−14 (Pb−Free)	25 Units/Rail
LM2901DG	SOIC−14 (Pb−Free)	55 Units/Rail
LM2901DR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM2901EDR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM2901DTBR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
LM2901NG	PDIP−14 (Pb−Free)	25 Units/Rail
LM2901VDG	SOIC−14 (Pb−Free)	55 Units/Tube
LM2901VDR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
LM2901VDTBR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
LM2901VNG	PDIP−14 (Pb−Free)	25 Units/Rail
NCV2901DR2G*	SOIC−14 (Pb−Free)	2500 / Tape & Reel
NCV2901DTBR2G*	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
NCV2901CTR*	Bare Die	6000 / Tape & Reel
MC3302DG	SOIC−14 (Pb−Free)	55 Units/Tube
MC3302DR2G	SOIC−14 (Pb−Free)	2500 / Tape & Reel
MC3302DTBR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
MC3302PG	PDIP−14 (Pb−Free)	25 Units/Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

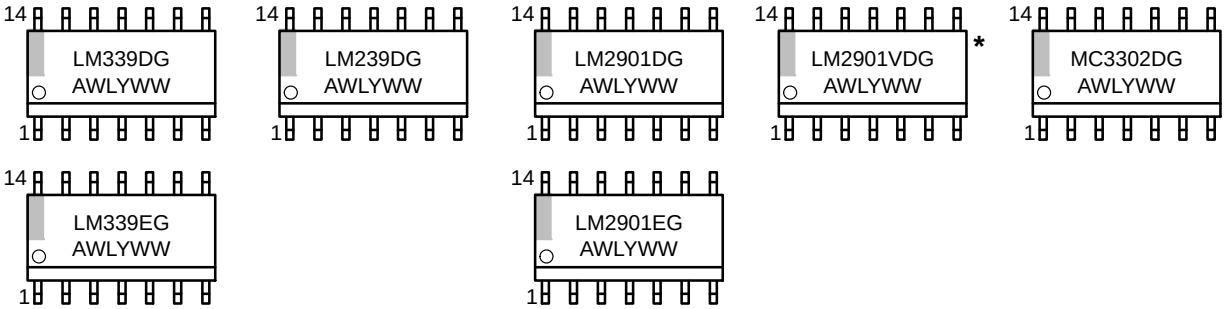
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

MARKING DIAGRAMS

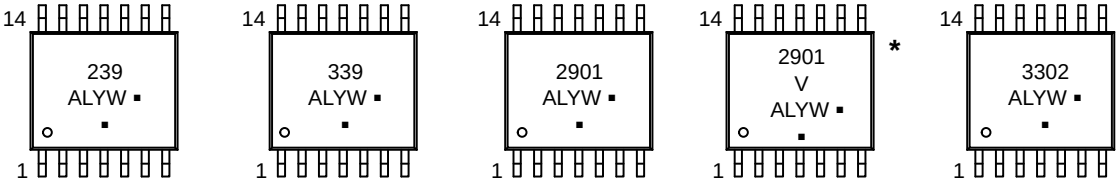
PDIP−14
N, P SUFFIX
CASE 646



SOIC−14
D SUFFIX
CASE 751A



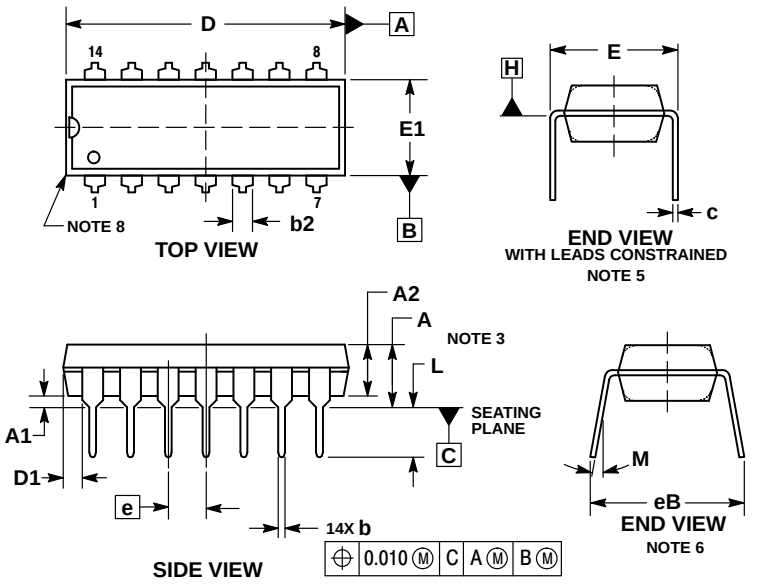
TSSOP−14
DTB SUFFIX
CASE 948G



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or ▪ = Pb−Free Package
(Note: Microdot may be in either location)
*This marking diagram also applies to NCV2901.

PACKAGE DIMENSIONS

PDIP−14
CASE 646−06
ISSUE S

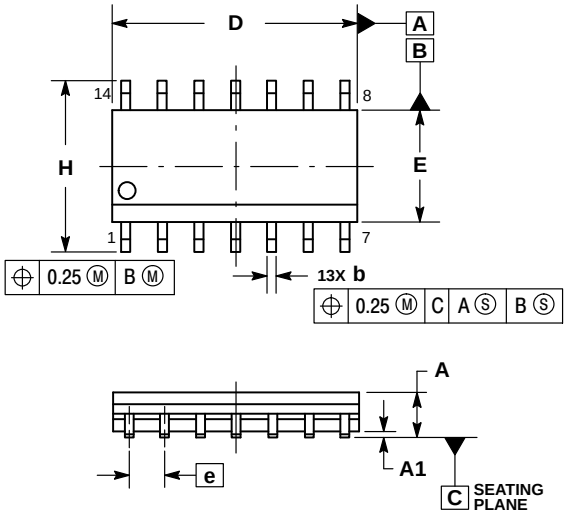


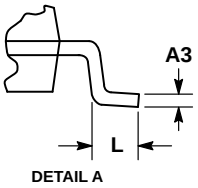
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS−3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

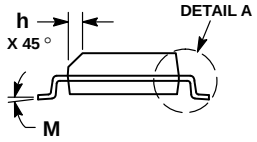
	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	−−−−	0.210	−−−	5.33
A1	0.015	−−−−	0.38	−−−
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52 TYP	
C	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005	−−−−	0.13	−−−
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	−−−−	0.430	−−−	10.92
L	0.115	0.150	2.92	3.81
M	−−−−	10°	−−−	10°

PACKAGE DIMENSIONS

SOIC−14
CASE 751A−03
ISSUE K



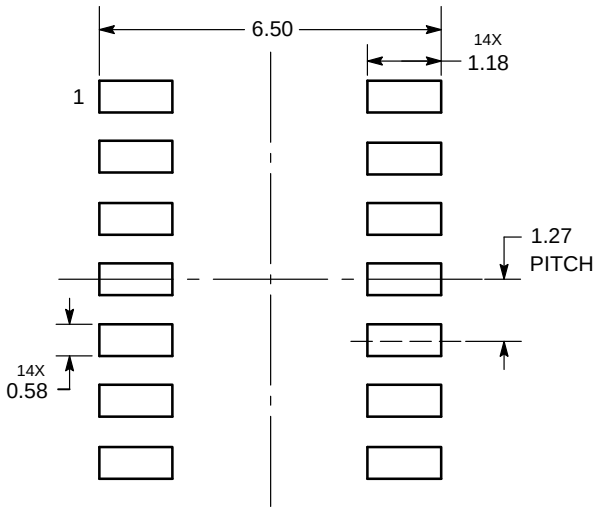




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0 °	7 °	0 °	7 °

SOLDERING FOOTPRINT*

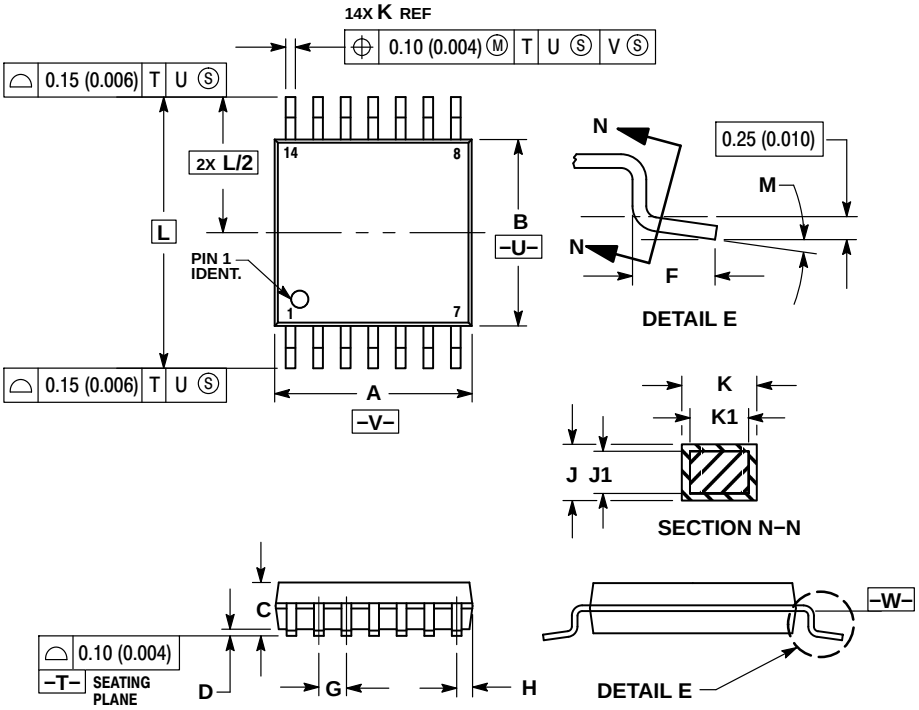


DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

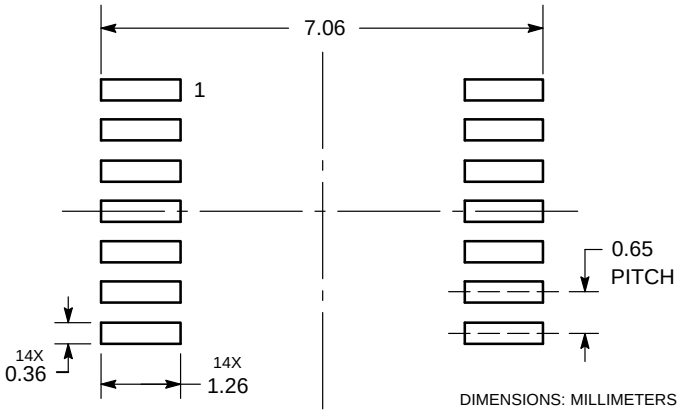
TSSOP−14
CASE 948G
ISSUE B



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	−−−	1.20	−−−	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

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